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SN74ALVC164245 16-BIT 2.5-V TO 3.3-V/3.3-V TO 5-V LEVEL-SHIFTING TRANSCEIVER WITH 3-STATE OUTPUTS

SCAS416P-MARCH 1994-REVISED NOVEMBER 2005

FEATURES

- Member of the Texas Instruments Widebus™
 Family
- Max t_{pd} of 5.8 ns at 3.3 V
- ±24-mA Output Drive at 3.3 V
- Control Inputs V_{IH}/V_{IL} Levels Are Referenced to V_{CCA} Voltage
- Latch-Up Performance Exceeds 250 mA Per JESD 17

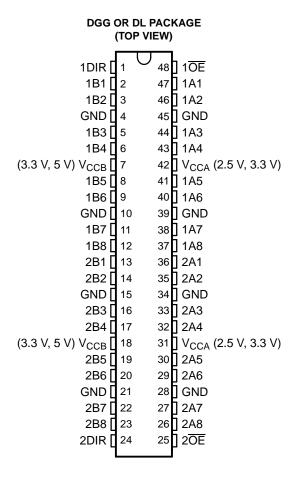
NOTE: New and improved versions of the SN74ALVC164245 are available. The new part numbers are SN74LVC16T245 and SN74LVCH16T245 and should be considered for new designs.

DESCRIPTION/ORDERING INFORMATION

This 16-bit (dual-octal) noninverting bus transceiver contains two separate supply rails. B port has V_{CCB} , which is set to operate at 3.3 V and 5 V. A port has V_{CCA} , which is set to operate at 2.5 V and 3.3 V. This allows for translation from a 2.5-V to a 3.3-V environment, and vice versa, or from a 3.3-V to a 5-V environment, and vice versa.

The SN74ALVC164245 is designed for asynchronous communication between data buses. The control circuitry (1DIR, 2DIR, $1\overline{OE}$, and $2\overline{OE}$) is powered by V_{CCA} .

To ensure the high-impedance state during power up or power down, the output-enable (\overline{OE}) input should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



ORDERING INFORMATION

T _A	PACKAC	3E ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	FBGA – GRD	Tape and reel	74ALVC164245GRDR	VC4245
	FBGA – ZRD (Pb-free)	rape and reer	74ALVC164245ZRDR	V C4243
		Tube of 25	SN74ALVC164245DL	
	SSOP – DL	Reel of 1000	SN74ALVC164245DLR	ALVC164245
		Reel of 1000	74ALVC164245DLRG4	
–40°C to 85°C		Reel of 2000	SN74ALVC164245DGGR	
	TSSOP – DGG	Reel of 2000	74ALVC164245DGGRG4	ALVC164245
	1330F - DGG	Reel of 250	SN74ALVC164245DGGT	ALVC104245
		Reel of 250	74ALVC164245DGGTE4	
	VFBGA – GQL	Reel of 1000	SN74ALVC164245KR	VC4245
	VFBGA – ZQL (Pb-free)	Veel of 1000	74ALVC164245ZQLR	V C4240

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The logic levels of the direction-control (DIR) input and the output-enable (\overline{OE}) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports always is active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ} .

GQL OR ZQL PACKAGE (TOP VIEW)

		1	2	3	4	5	6	
Α	(()		()	$\overline{\circ}$	Ì
В		()	()	()	()	()	()	ı
С		()	()	()	()	()	()	ı
D		()	()	()	()	()	()	ı
Е		()	()			()	()	ı
F		•	()			()	• •	ı
G					()			ı
Н		٠,	٠,	٠,	()	٠,	• •	ı
J		•	• •	•	\odot	•	• •	ı
K	l	()	()	()	()	()	\circ	J
	_						_	

TERMINAL ASSIGNMENTS⁽¹⁾ (56-Ball GQL/ZQL Package)

	1	2	3	4	5	6
Α	1DIR	NC	NC	NC	NC	1 OE
В	1B2	1B1	GND	GND	1A1	1A2
С	1B4	1B3	V_{CCB}	V_{CCA}	1A3	1A4
D	1B6	1B5	GND	GND	1A5	1A6
Е	1B8	1B7			1A7	1A8
F	2B1	2B2			2A2	2A1
G	2B3	2B4	GND	GND	2A4	2A3
Н	2B5	2B6	V_{CCB}	V_{CCA}	2A6	2A5
J	2B7	2B8	GND	GND	2A8	2A7
K	2DIR	NC	NC	NC	NC	2 OE

(1) NC - No internal connection

GRD OR ZRD PACKAGE (TOP VIEW)

			•			-,		
	_	1	2	3	4	5	6	_
	/	\sim	\sim	\sim	$\overline{}$	\sim	\sim	_
Α				\bigcirc				
В		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	()	
С		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	()	
D		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	()	
Е		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
F		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
G		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
н		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
J		\bigcirc	\bigcirc	\bigcirc	()	()	\bigcirc	
	`							_

TERMINAL ASSIGNMENTS⁽¹⁾ (54-Ball GRD/ZRD Package)

	1	2	3	4	5	6	
Α	1B1	NC	1DIR	1 OE	NC	1A1	
В	1B3	1B2	NC	NC	1A2	1A3	
С	1B5	1B4	V _{CCB}	V_{CCA}	1A4	1A5	
D	1B7	1B6	GND	GND	1A6	1A7	
E	2B1	1B8	GND	GND	1A8	2A1	
F	2B3	2B2	GND	GND	2A2	2A3	
G	2B5	2B4	V _{CCB}	V_{CCA}	2A4	2A5	
Н	2B7	2B6	NC	NC	2A6	2A7	
J	2B8	NC	2DIR	2 OE	NC	2A8	

(1) NC - No internal connection

FUNCTION TABLE⁽¹⁾ (EACH 8-BIT SECTION)

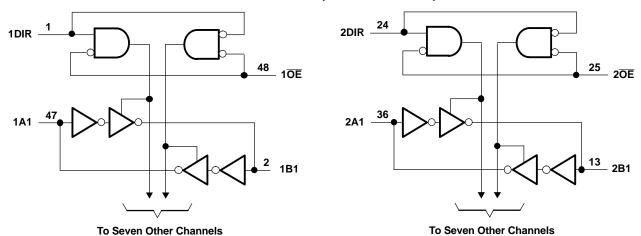
CONTRO	L INPUTS	OUTPUT (CIRCUITS	OPERATION	
ŌĒ	DIR	A PORT			
L	L	Enabled	Hi-Z	B data to A bus	
L	Н	Hi-Z	Enabled	A data to B bus	
Н	Х	Hi-Z	Hi-Z	Isolation	

(1) Input circuits of the data I/Os always are active.



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LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings(1)

over operating free-air temperature range for V_{CCB} at 5 V and V_{CCA} at 3.3 V (unless otherwise noted)

			MIN	MAX	UNIT
.,	Supply voltage range	V _{CCA}	-0.5	4.6	V
V _{CC}	Supply voltage range	V _{CCB}	-0.5	6	V
-		Except I/O ports ⁽²⁾	-0.5 6 -0.5 6 -0.5 V _{CCA} + 0.5 -0.5 V _{CCB} + 0.5 -50 -50		
V_{I}	Input voltage range	I/O port A ⁽³⁾	-0.5	$V_{CCA} + 0.5$	V
		I/O port B ⁽²⁾	-0.5	-0.5 4.6 -0.5 6 -0.5 6 -0.5 V _{CCA} + 0.5 -0.5 V _{CCB} + 0.5 -50 -50 ±50 ±100 70 63	
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			-0.5 4.6 -0.5 6 -0.5 6 -0.5 V _{CCA} + 0.5 -0.5 V _{CCB} + 0.5 -50 -50 ±50 ±100 70 63 42	mA
	Continuous current through each V _{CC} or	GND		±100	mA
		DGG package		70	
0	Dealer on the arread income days a (4)	DL package		63	
θ_{JA}	Package thermal impedance (4)	GQL/ZQL package		42	°C/W
		GRD/ZRD package		36	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ This value is limited to 6 V maximum.

⁽³⁾ This value is limited to 4.6 V maximum.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



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Recommended Operating Conditions⁽¹⁾

for $\rm V_{\rm CCB}$ at 3.3 V and 5 V

				MIN	MAX	UNIT
V _{CCB}	Supply voltage			3	5.5	V
V_{IH}	High-level input voltage			2		V
V	Low-level input voltage	V _{CCB} = 3 V to 3.6 V			0.7	V
·L	Low-level input voltage	V _{CCB} = 4.5 V to 5.5 V			0.8	V
V_{IB}	Input voltage			0	V_{CCB}	V
V_{OB}	Output voltage			0	V_{CCB}	V
I _{OH}	High-level output current				-24	mA
I_{OL}	Low-level output current				24	mA
$\Delta t/\Delta v$	Input transition rise or fall rat	e			10	ns/V
T _A	Operating free-air temperatu	re		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Recommended Operating Conditions⁽¹⁾

for V_{CCA} at 2.5 V and 3.3 V

			MIN	MAX	UNIT	
V_{CCA}	Supply voltage		2.3	3.6	V	
\/	Lligh lovel input voltage	V _{CCA} = 2.3 V to 2.7 V	1.7		V	
V _{IH}	High-level input voltage	V _{CCA} = 3 V to 3.6 V	2		V	
\/	Low level input veltage	V _{CCA} = 2.3 V to 2.7 V		0.7	V	
V _{IL}	, ,	V _{CCA} = 3 V to 3.6 V		0.8	V	
V_{IA}	Input voltage		0	V_{CCA}	V	
V _{OA}	Output voltage		0	V_{CCA}	V	
	Lligh lovel cutout current	V _{CCA} = 2.3 V		-18	mA	
I _{OH}	High-level output current	V _{CCA} = 3 V		-24	mA	
	Low lovel output ourrent	V _{CCA} = 2.3 V		18	A	
I _{OL}	Low-level output current	V _{CCA} = 3 V		24	mA	
Δt/Δν	Input transition rise or fall rate			10	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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Electrical Characteristics

over recommended operating free-air temperature range for V_{CCA} = 2.7 V to 3.6 V and V_{CCB} = 4.5 V to 5.5 V (unless otherwise noted)

P	ARAMETER	TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP ⁽¹⁾	MAX	UNIT	
		$I_{OH} = -100 \mu A$	2.7 V to 3.6 V		V _{CC} - 0.2				
	B to A	I _{OH} = -12 mA	2.7 V		2.2				
	BIOA	10H = -12 IIIA	3 V		2.4				
V		$I_{OH} = -24 \text{ mA}$	3 V		2			V	
V _{OH}		1. 100 4		4.5 V	4.3			V	
	A to D	$I_{OH} = -100 \mu\text{A}$		5.5 V	5.3				
	A to B	1 24 mA		4.5 V	3.7				
		$I_{OH} = -24 \text{ mA}$		5.5 V	4.7				
	B to A	I _{OL} = 100 μA	2.7 V to 3.6 V				0.2	0.2	
		I _{OL} = 12 mA	2.7 V				0.4		
V_{OL}		I _{OL} = 24 mA	3 V				0.55	V	
	A +- D	I _{OL} = 100 μA		4.5 V to 5.5 V			0.2	.]	
	A to B	I _{OL} = 24 mA		4.5 V to 5.5 V			0.55		
I	Control inputs	$V_I = V_{CCA}/V_{CCB}$ or GND	3.6 V	5.5 V			±5	μΑ	
I _{OZ} ⁽²⁾	A or B port	$V_O = V_{CCA}/V_{CCB}$ or GND	3.6 V	5.5 V			±10	μΑ	
I_{CC}		$V_I = V_{CCA}/V_{CCB}$ or GND, $I_O = 0$	3.6 V	5.5 V			40	μΑ	
Δl _{CC} (3	3)	One input at V _{CCA} /V _{CCB} – 0.6 V, Other inputs at V _{CCA} /V _{CCB} or GND	3 V to 3.6 V	4.5 V to 5.5 V			750	μΑ	
Ci	Control inputs	$V_I = V_{CCA}/V_{CCB}$ or GND	3.3 V	5 V		6.5		pF	
C _{io}	A or B port	$V_O = V_{CCA}/V_{CCB}$ or GND	3.3 V	3.3 V		8.5		pF	

- Typical values are measured at $V_{CCA} = 3.3 \text{ V}$ and $V_{CCB} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$. For I/O ports, the parameter I_{OZ} includes the input leakage current. This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than at 0 or the associated V_{CC} .

Electrical Characteristics

over recommended operating free-air temperature range for $V_{CCA} = 2.3 \text{ V}$ to 2.7 V and $V_{CCB} = 3 \text{ V}$ to 3.6 V (unless otherwise noted)

P	ARAMETER	TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	MAX	UNIT	
		I _{OH} = -100 μA	2.3 V to 2.7 V	3 V to 3.6 V	V _{CCA} - 0.2			
	B to A	$I_{OH} = -8 \text{ mA}$	2.3 V	3 V to 3.6 V	1.7			
V_{OH}		I _{OH} = −12 mA	2.7 V	3 V to 3.6 V	1.8		V	
	A to B	$I_{OH} = -100 \mu A$	2.3 V to 2.7 V	3 V to 3.6 V	V _{CCB} - 0.2			
		I _{OH} = -18 mA	2.3 V to 2.7 V	3 V	2.2			
	B to A	I _{OL} = 100 μA	2.3 V to 2.7 V	3 V to 3.6 V		0.2		
\/		I _{OL} = 12 mA	2.3 V	3 V to 3.6 V		0.6	V	
V _{OL}	A to D	$I_{OL} = 100 \mu A$	2.3 V to 2.7 V	3 V to 3.6 V		0.2	.2	
	A to B	I _{OL} = 18 mA	2.3 V	3 V		0.55		
I	Control inputs	$V_I = V_{CCA}/V_{CCB}$ or GND	2.3 V to 2.7 V	3 V to 3.6 V		±5	μΑ	
$I_{OZ}^{(1)}$	A or B port	$V_O = V_{CCA}/V_{CCB}$ or GND	2.3 V to 2.7 V	3 V to 3.6 V		±10	μΑ	
I_{CC}		$V_I = V_{CCA}/V_{CCB}$ or GND, $I_O = 0$	2.3 V to 2.7 V	3 V to 3.6 V		20	μΑ	
$\Delta I_{CC}^{(2)}$	2)	One input at $V_{CCA}/V_{CCB} - 0.6 \text{ V}$, Other inputs at V_{CCA}/V_{CCB} or GND	2.3 V to 2.7 V	3 V to 3.6 V		750	μΑ	

- For I/O ports, the parameter I_{OZ} includes the input leakage current.
- This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than at 0 or the associated V_{CC} .



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Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 4)

PARAMETER			V _{CCB} = 3.3 V ± 0.3 V	V _{CCB} = 5 \	/ ± 0.5 V	
	FROM (INPUT)	TO (OUTPUT)	V _{CCA} = 2.5 V ± 0.2 V	V _{CCA} = 2.7 V	V _{CCA} = 3.3 V ± 0.3 V	UNIT
			MIN MAX	MIN MAX	MIN MA	X
+	A	В	7.6	5.9	1 5.	
t _{pd}	В	Α	7.6	6.7	1.2 5.	ns 8
t _{en}	ŌĒ	В	11.5	9.3	1 8.	9 ns
t _{dis}	ŌĒ	В	10.5	9.2	2.1 9.	5 ns
t _{en}	ŌĒ	Α	12.3	10.2	2 9.	1 ns
t _{dis}	ŌĒ	Α	9.3	9	2.9 8.	6 ns

Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	$V_{CCB} = 3.3 \text{ V}$ $V_{CCA} = 2.5 \text{ V}$ TYP	$V_{CCB} = 5 V$ $V_{CCA} = 3.3 V$ TYP	UNIT
		Outputs enabled (B)	$C_1 = 50 \text{ pF}, f = 10 \text{ MHz}$	55	56	
_	Dower discination conscitance	Outputs disabled (B)	$C_L = 50 \text{ pr}, \Gamma = 10 \text{ Winz}$	27	6	~F
C _{pd}	Power dissipation capacitance	Outputs enabled (A)	C F0 pF f 10 MU =	118	56	pF
		Outputs disabled (A)	$C_L = 50 \text{ pF}, f = 10 \text{ MHz}$	58	6	



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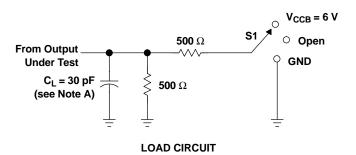
POWER-UP CONSIDERATIONS(1)

TI level-translation devices offer an opportunity for successful mixed-voltage signal design. A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies caused by improperly biased device pins. Take these precautions to guard against such power-up problems:

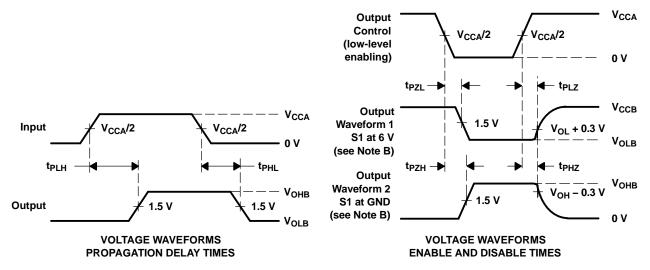
- 1. Connect ground before any supply voltage is applied.
- 2. Power up the control side of the device (V_{CCA} for all four of these devices).
- 3. Tie \overline{OE} to V_{CCA} with a pullup resistor so that it ramps with V_{CCA} .
- 4. Depending on the direction of the data path, DIR can be high or low. If DIR high is needed (A data to B bus), ramp it with V_{CCA} . Otherwise, keep DIR low.
- (1) Refer to the TI application report, Texas Instruments Voltage-Level-Translation Devices, literature number SCEA021.



PARAMETER MEASUREMENT INFORMATION V_{CCA} = 2.5 V \pm 0.2 V to V_{CCB} = 3.3 V \pm 0.3 V



TEST	S 1
t _{pd}	Open
t _{PLZ} /t _{PZL}	$V_{CCB} = 6 V$
t _{PHZ} /t _{PZH}	GND

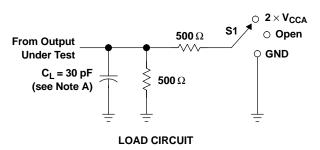


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

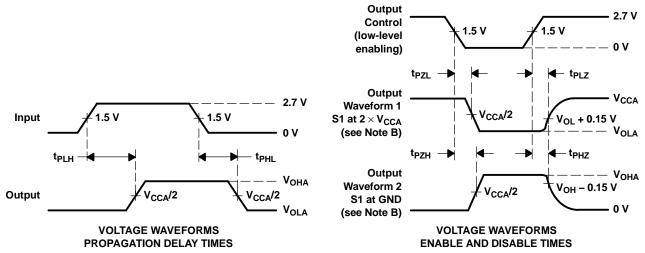
Figure 1. Load Circuit and Voltage Waveforms

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PARAMETER MEASUREMENT INFORMATION V_{CCB} = 3.3 V \pm 0.3 V to V_{CCA} = 2.5 V \pm 0.2 V



TEST	S1
t _{pd}	Open
t _{PLZ} /t _{PZL}	$2 \times V_{CCA}$
t _{PHZ} /t _{PZH}	GND

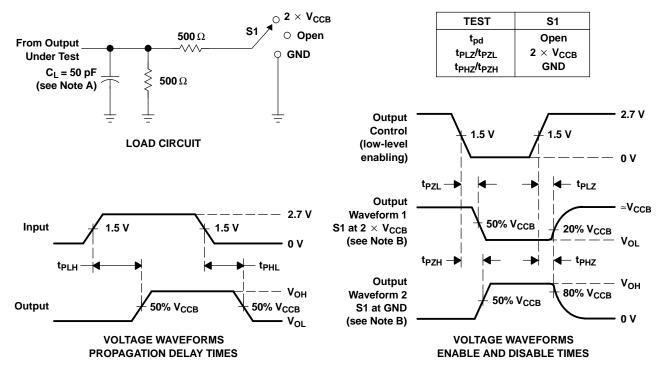


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \le 10 MHz, $Z_0 = 50 \,\Omega$, $t_r \le 2 \,$ ns, $t_f \le 2 \,$ ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 2. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION V_{CCA} = 3.3 V \pm 0.3 V to V_{CCB} = 5 V \pm 0.5 V



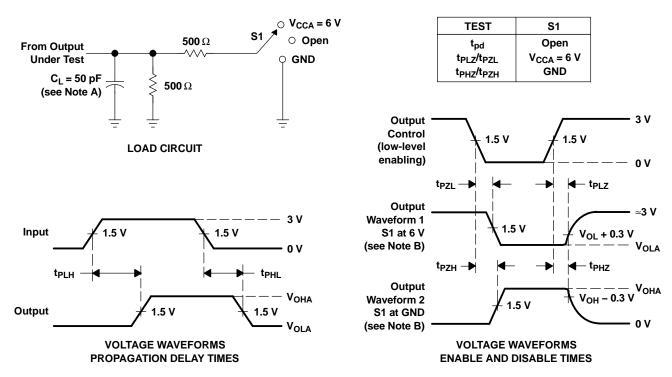
NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{f} \leq$ 2.5 ns. $t_{f} \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 3. Load Circuit and Voltage Waveforms

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PARAMETER MEASUREMENT INFORMATION V_{CCB} = 5 V \pm 0.5 V to V_{CCA} = 2.7 V and 3.3 V \pm 0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{Ω} = 50 Ω , $t_{r} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 4. Load Circuit and Voltage Waveforms





17-May-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
74ALVC164245DGGRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
74ALVC164245DGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
74ALVC164245DGGTE4	ACTIVE	TSSOP	DGG	48	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
74ALVC164245DGGTG4	ACTIVE	TSSOP	DGG	48	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
74ALVC164245DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
74ALVC164245DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
74ALVC164245GRDR	OBSOLETE	BGA MICROSTAR JUNIOR	GRD	54		TBD	Call TI	Call TI	-40 to 85		
74ALVC164245ZQLR	ACTIVE	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VC4245	Samples
74ALVC164245ZRDR	ACTIVE	BGA MICROSTAR JUNIOR	ZRD	54	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VC4245	Samples
SN74ALVC164245-W	ACTIVE	WAFERSALE	YS	0		TBD	Call TI	Call TI			Samples
SN74ALVC164245DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
SN74ALVC164245DGGT	ACTIVE	TSSOP	DGG	48	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
SN74ALVC164245DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
SN74ALVC164245DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC164245	Samples
SN74ALVC164245KR	OBSOLETE	BGA MICROSTAR JUNIOR	GQL	56		TBD	Call TI	Call TI	-40 to 85		



17-May-2014

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74ALVC164245:

Enhanced Product: SN74ALVC164245-EP

NOTE: Qualified Version Definitions:



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PACKAGE OPTION ADDENDUM

17-May-2014

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74ALVC164245ZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1
74ALVC164245ZRDR	BGA MI CROSTA R JUNI OR	ZRD	54	1000	330.0	16.4	5.8	8.3	1.55	8.0	16.0	Q1
SN74ALVC164245DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74ALVC164245DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1

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*All dimensions are nominal

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Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)				
74ALVC164245ZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	336.6	336.6	28.6				
74ALVC164245ZRDR	BGA MICROSTAR JUNIOR	ZRD	54	1000	336.6	336.6	28.6				
SN74ALVC164245DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0				
SN74ALVC164245DLR	SSOP	DL	48	1000	367.0	367.0	55.0				

ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

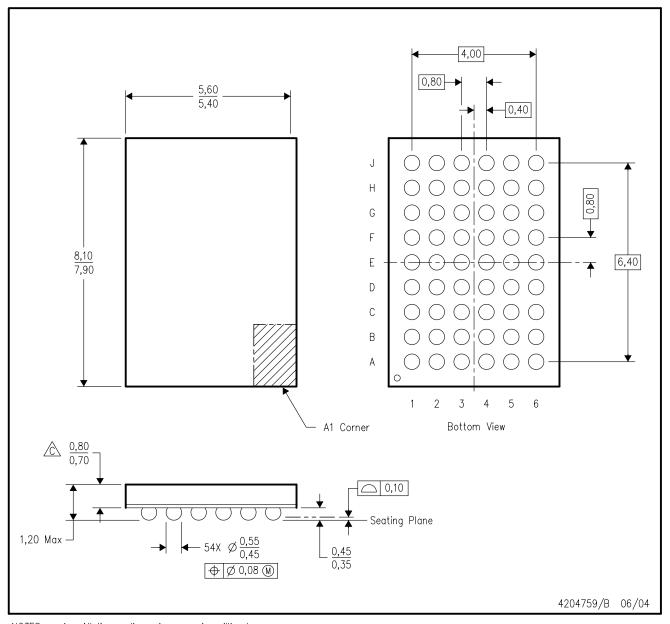
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is Pb-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).

MicroStar Junior is a trademark of Texas Instruments



GRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



 $\hbox{NOTES:} \quad \hbox{A. All linear dimensions are in millimeters.}$

B. This drawing is subject to change without notice.

Falls within JEDEC MO-205 variation DD.

D. This package is tin-lead (SnPb). Refer to the 54 ZRD package (drawing 4204760) for lead-free.



ZRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



 $\hbox{NOTES:} \quad \hbox{A. All linear dimensions are in millimeters.}$

- B. This drawing is subject to change without notice.
- Falls within JEDEC MO-205 variation DD.
- D. This package is lead-free. Refer to the 54 GRD package (drawing 4204759) for tin-lead (SnPb).



DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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